



# AH342

## Active High/Low Complementary Output Hall-effect Latch

### ■ Features

- Digital dual complementary sink/source outputs
- Reverse Voltage Polarity protection for full supply range.
- High output current capability
- Low profile 4 pin SIP package

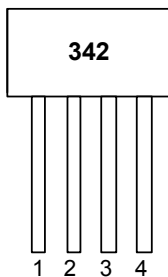
### ■ Applications

- Conveyors
- Motor control
- Power sensing
- Linear or rotary motion detection
- RPM sensing

### ■ General Description

The AH342 is a bipolar latching hall IC with a pair of complementary push/pull outputs. A dual hall element is used to offset stress induced noise and drift. The robust outputs are capable of sourcing up to 7.4mA and sinking up to 4.4mA. The device contains inherent reverse polarity protection up to the full power supply range.

### ■ Pin Assignment



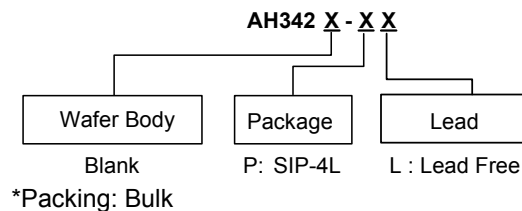
Front View

- 1 : Vcc
- 2 : DO
- 3 : DOB
- 4 : Vss

### ■ Pin Descriptions

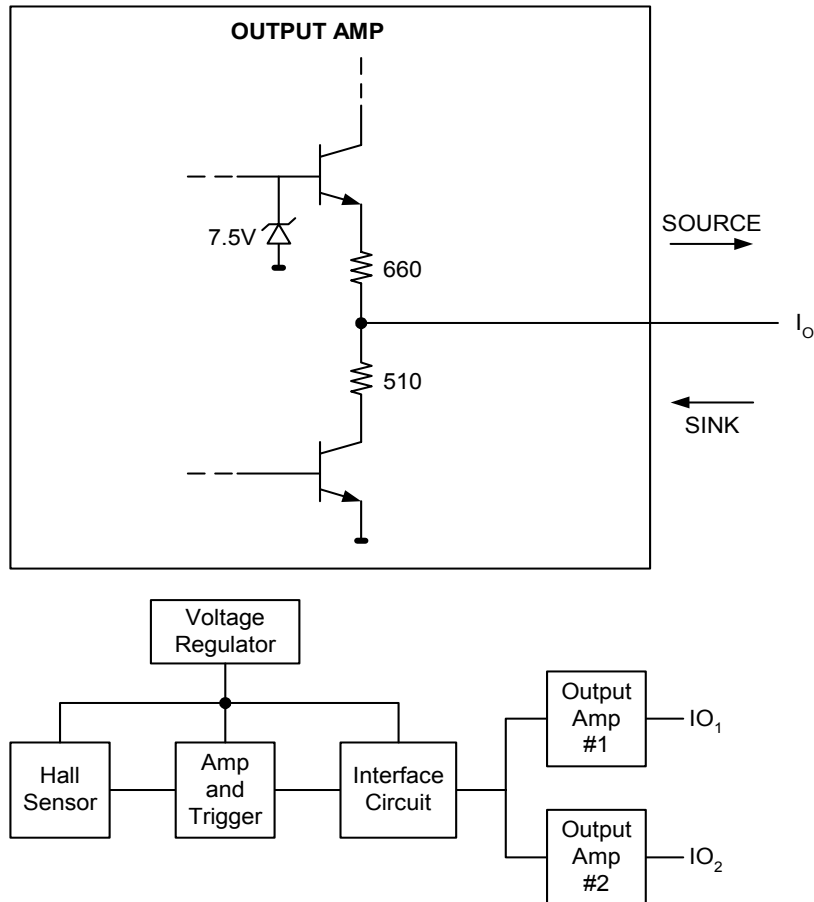
Name	P/I/O	Pin #	Description
Vcc	P	1	Positive Supply Power
DO	O	2	Output Pin
DOB	O	3	Output Pin
Vss	P	4	Ground

### ■ Ordering Information



## Active High/Low Complementary Output Hall-effect Latch

### ■ Block Diagram



### ■ Absolute Maximum Ratings (Note 1)

Characteristics	Sym.	Conditions	Values	Unit
Supply voltage	$V_{CC}$	-40°C to 125°C	±28	V
Voltage Externally Applied to Output	$V_{OUT}$	-40°C to 125°C	-1.2 to 5	V
Output Current	$I_c$		±10	mA
Magnetic Flux density	B	No limit; the circuit cannot be damaged by magnetic overdrive	Unlimited	
Operation Temperature	$T_{OPR}$		-40 to 125	°C
Storage Temperature	$T_{STG}$	No power applied	-40 to 150	°C

**Note 1:** Absolute maximum ratings are the extreme limits that the device will withstand without damage to the device. However, the electrical and magnetic characteristics are not guaranteed as the maximum limits (above recommended operating conditions) are approached nor will the device necessarily operate at absolute maximum rating.



## Active High/Low Complementary Output Hall-effect Latch

### ■ Electrical Characteristics (Note 2, 3)

Characteristic	Sym.	Conditions	24°C ± 2°C			-40°C to 125°C			Units
			Min	Typ.	Max	Min	Typ.	Max	
Supply Voltage	V <sub>CC</sub>		4.5	-	28	4.5	-	28	V
Supply Current	I <sub>CC</sub>	28V±0.5% supply	4	4.5	6	3	4.5	7	mA
<b>Output Voltage</b>									
#1 Sourcing	V <sub>OUT</sub>	Switch magnetically operated: No load 28V±0.5% supply. Switch magnetically released: No load 28V±0.5% supply.	6.0	7.0	7.5	-	-	-	V
#2 Sinking			0	0.1	0.2	-	-	-	
#1 Sinking			0	0.1	0.2	-	-	-	
#2 Sourcing			6.0	7.0	7.5	-	-	-	
Leakage (sink)	I <sub>Leak(sink)</sub>	Apply voltage 0.2V greater than measured output source voltage measure current, no load 28V±0.5% supply.	-	-	1.0	-	-	1.0	µA
<b>Output Current</b>									
#1 Sourcing	I <sub>OUT</sub>	Apply 2V to output and measure current. Switch magnetically operated, no load 28V±0.5%. Apply 2V to output and measure current. Switch magnetically released, no load 28V±0.5%.	5.5	7.4	8.0	5.0	7.4	8.5	mA
#2 Sinking			2.8	3.4	4.7	2.4	3.4	5.0	
#1 Sinking			2.8	3.4	4.7	2.4	3.4	5.0	
#2 Sourcing			5.5	7.4	8.0	5.0	7.4	8.5	
<b>Output Switching Time</b>									
Fall Time	t <sub>f</sub>	90% to 10%; no load 28V±0.5% Supply	-	-	-	-	-	1.0	µs
Rise Time	t <sub>r</sub>	10% to 90%; no load 28V±0.5% Supply	-	-	-	-	-	1.0	

### ■ Magnetic Characteristics (Ta=+25°C) (Note 2, 3)

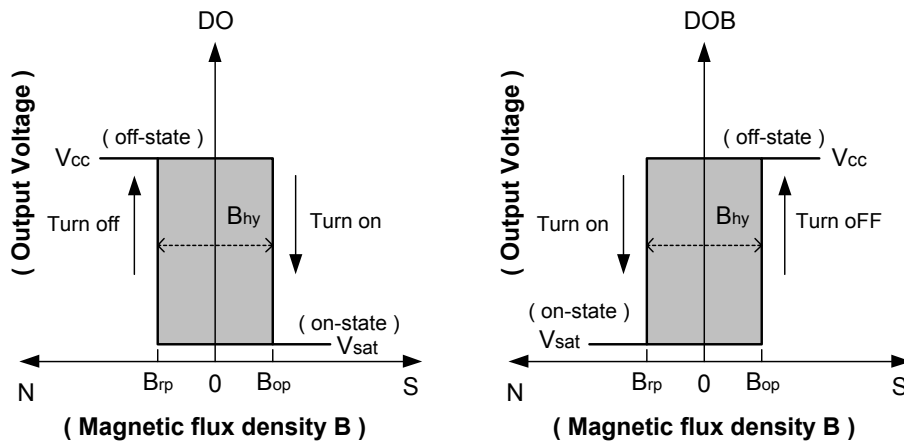
(1mT = 10 Gauss)

Characteristic	Sym.	24°C ± 2°C Vs=12Vdc ± 0.5%Vdc		-40°C to 125°C Vs=4.5Vdc to 28Vdc		Unit
		Min.	Max.	Min.	Max.	
Operate Point	Bop	40	120	30	150	Gauss
Release Point	Brp	-120	-40	-150	-30	Gauss
Hysteresis	Bhy	120	200	120	200	Gauss

**Note 2:** All the parameters are tested under the 25°C only. The operation temperature (-40°C to 125°C) is guaranteed by design, it is typical value.

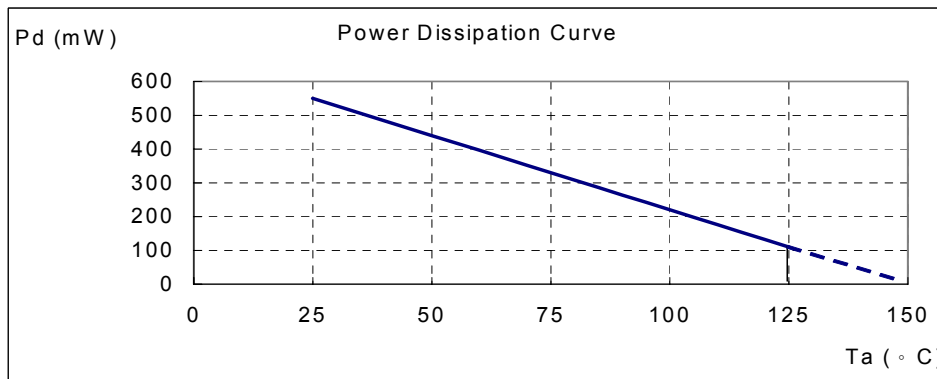
**Note 3:** The magnetic field strength (gauss) required to cause the switch to change state (operate and release) will be as specified in the magnetic characteristics. To test the switch against the specified magnetic characteristics the switch must be placed in a uniform magnetic field.

## Active High/Low Complementary Output Hall-effect Latch



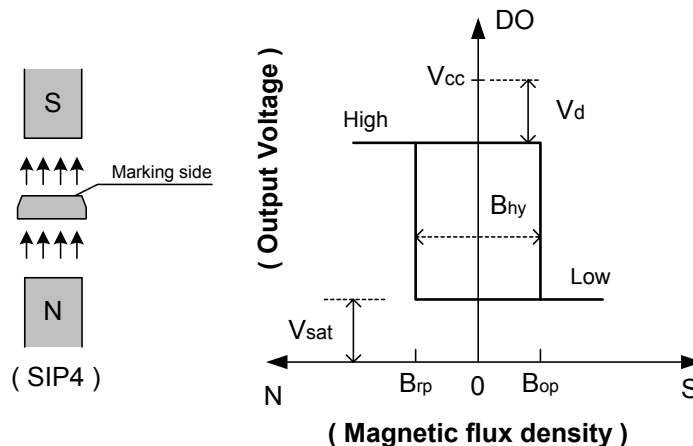
### ■ Performance Characteristics (SIP4)

Ta (°C)	25	50	60	70	80	85	90	95	100
Pd (mW)	550	440	396	352	308	286	264	242	220
Ta (°C)	105	110	115	120	125	130	135	140	150
Pd (mW)	198	176	154	132	110	88	66	44	0



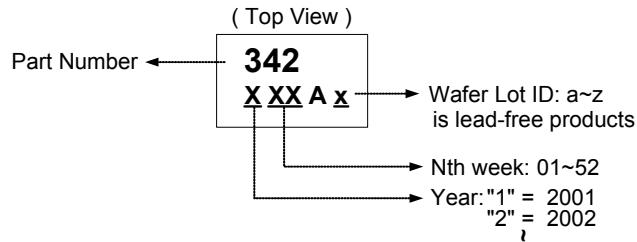
Note : SIP-4L package.

### ■ Operating Characteristics



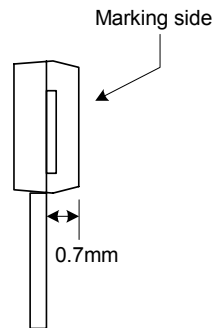
## Active High/Low Complementary Output Hall-effect Latch

### ■ Marking Information

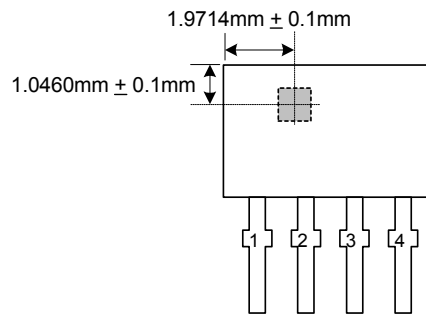


### ■ Package Information

Active Area Depth



Package Sensor Location



Package Dimension

